

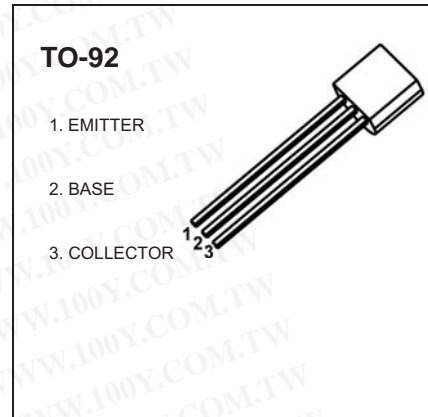
## TO-92 Plastic-Encapsulate Transistors

### S9014 TRANSISTOR (NPN)

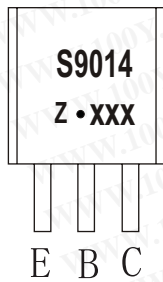
#### FEATURES

- High Total Power Dissipation. ( $P_C=0.45W$ )
- High  $h_{FE}$  and Good Linearity
- Complementary to S9015

勝特力材料 886-3-5753170  
 勝特力电子(上海) 86-21-34970699  
 勝特力电子(深圳) 86-755-83298787  
[Http://www.100y.com.tw](http://www.100y.com.tw)

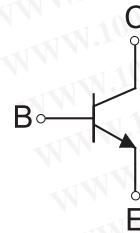


#### MARKING



S9014=Device code  
 Solid dot=Green molding compound device,  
 if none,the normal device  
 Z=Rank of  $h_{FE}$ ,  
 XXX=Code

#### Equivalent Circuit



#### ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
S9014	TO-92	Bulk	1000pcs/Bag
S9014-TA	TO-92	Tape	2000pcs/Box

#### MAXIMUM RATINGS ( $T_a=25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	50	V
$V_{CEO}$	Collector-Emitter Voltage	45	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current -Continuous	0.1	A
$P_D$	Collector Power Dissipation	450	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	277.7	$^{\circ}C / W$
$T_j$	Junction Temperature	150	$^{\circ}C$
$T_{stg}$	Storage Temperature	-55~+150	$^{\circ}C$

## ELECTRICAL CHARACTERISTICS

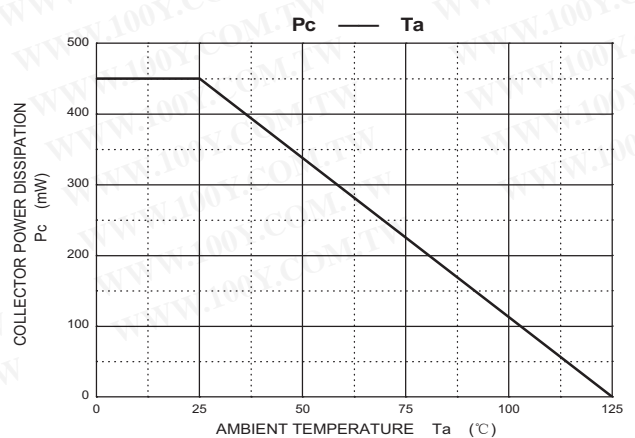
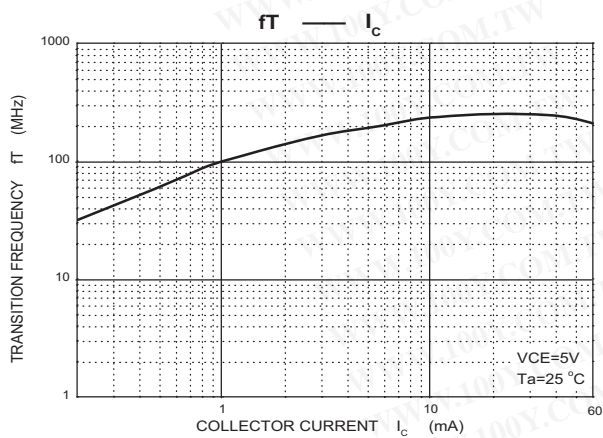
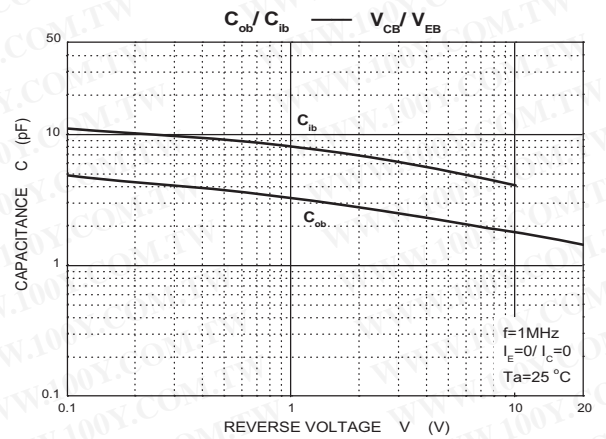
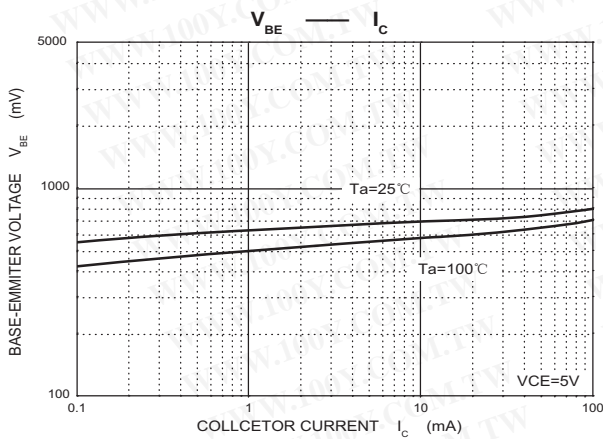
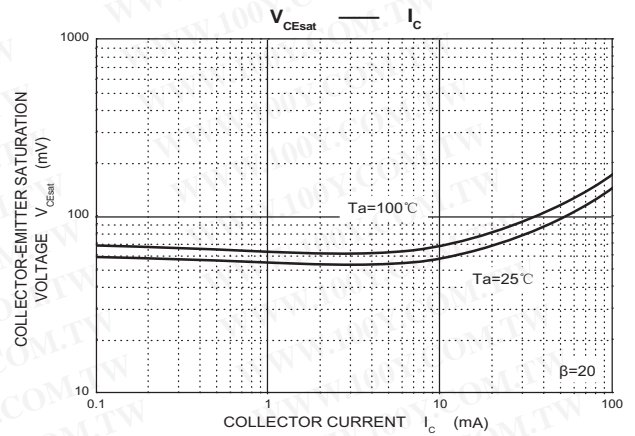
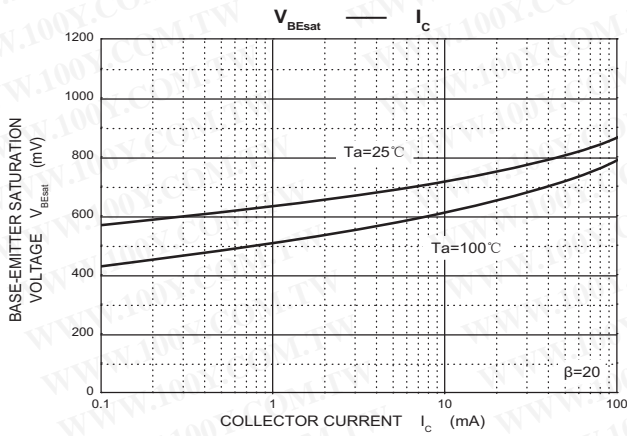
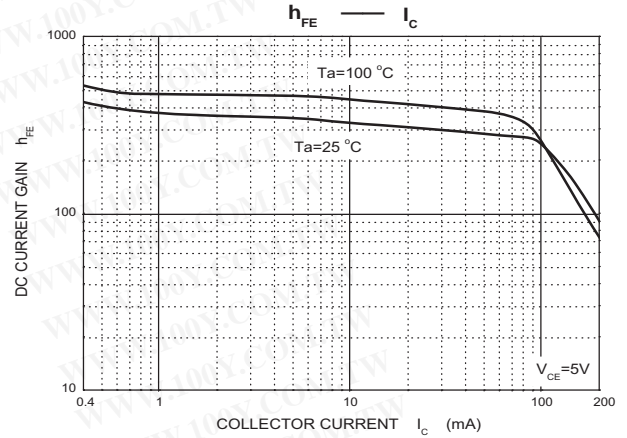
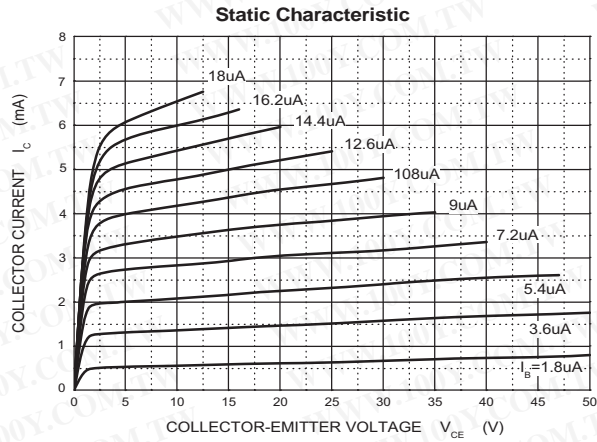
$T_a=25^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu\text{A}$ , $I_E=0$	50			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}$ , $I_B=0$	45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu\text{A}$ , $I_C=0$	5			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=50\text{V}$ , $I_E=0$			0.1	$\mu\text{A}$
Collector cut-off current	$I_{CEO}$	$V_{CE}=35\text{V}$ , $I_B=0$			1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=5\text{V}$ , $I_C=0$			0.1	$\mu\text{A}$
DC current gain	$h_{FE}$	$V_{CE}=5\text{V}$ , $I_C=1\text{mA}$	60		1000	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=100\text{mA}$ , $I_B=5\text{mA}$			0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=100\text{mA}$ , $I_B=5\text{mA}$			1	V
Transition frequency	$f_T$	$V_{CE}=5\text{V}$ , $I_C=10\text{mA}$ $f=30\text{MHz}$	150			MHz

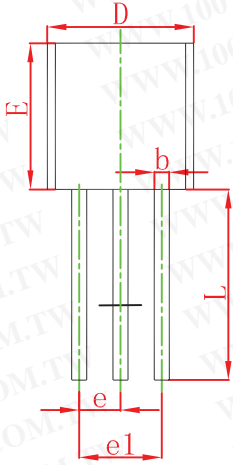
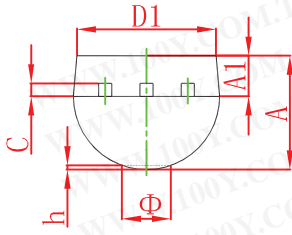
### CLASSIFICATION OF $h_{FE(1)}$

Rank	A	B	C	D
Range	60-150	100-300	200-600	400-1000

# Typical Characteristics

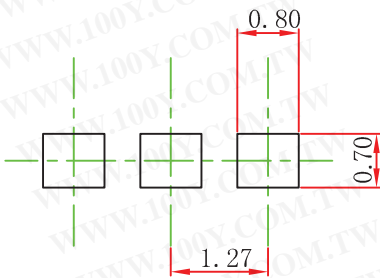


## TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

## TO-92 Suggested Pad Layout



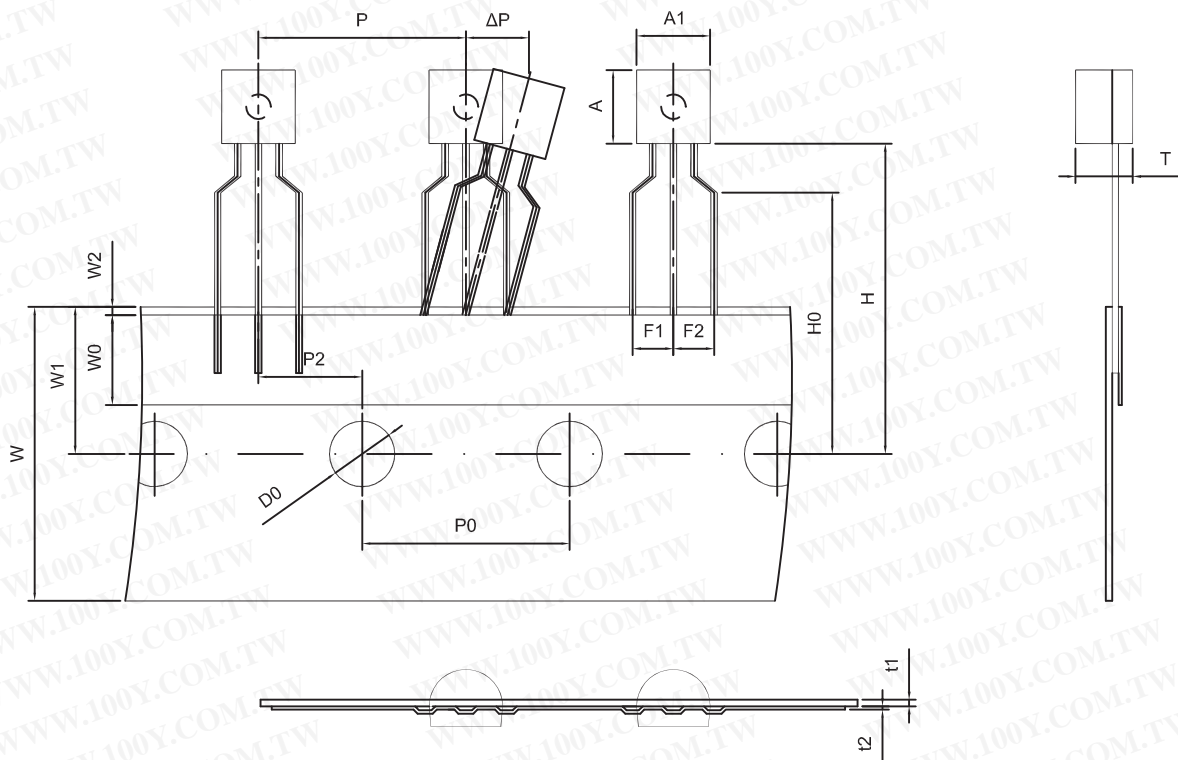
### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

### NOTICE

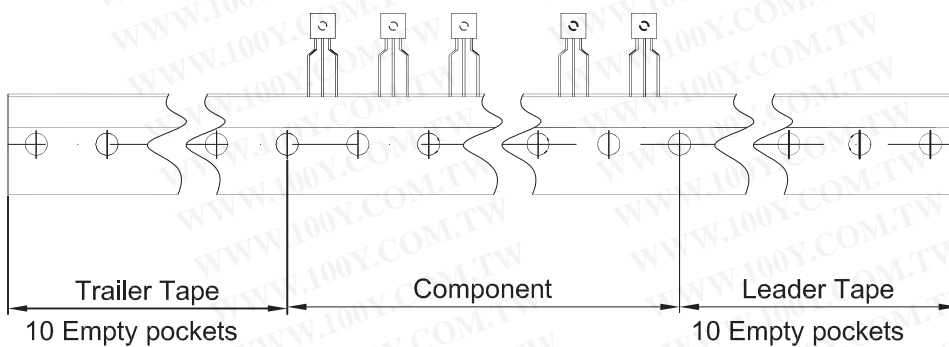
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TO-92 PACKAGE TAPEING DIMENSION



Dimiensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250